National Semiconductor

July 1998

54ABT273
Octal D-Type Flip-Flop

General Description

The 'ABT273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

- Eight edge-triggered D flip-flops
- Buffered common clock
- Buffered, asynchronous Master Reset
- See 'ABT377 for clock enable version
- See 'ABT373 for transparent latch version
- See 'ABT374 for TRI-STATE® version
- Output sink capability of 48 mA, source capability of 24 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Disable time less than enable time to avoid bus contention
- Standard Microcircuit Drawing (SMD) 5962-9321701

Ordering Code

Military	Package Number	Package Description
54ABT273J-QML	J20A	20-Lead Ceramic Dual-In-Line
54ABT273W-QML	W20A	20-Lead Cerpack
54ABT273E-QML	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

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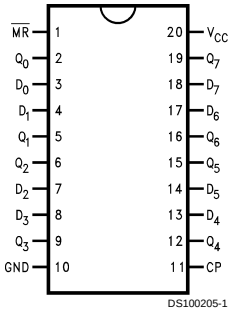
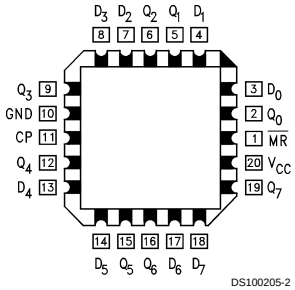
Connection Diagrams

Pin Assignment for DIP and Flatpack



DS100205-1

Pin Assignment for LCC



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Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset (Active LOW)
CP	Clock Pulse Input (Active Rising Edge)
Q_0–Q_7	Data Outputs

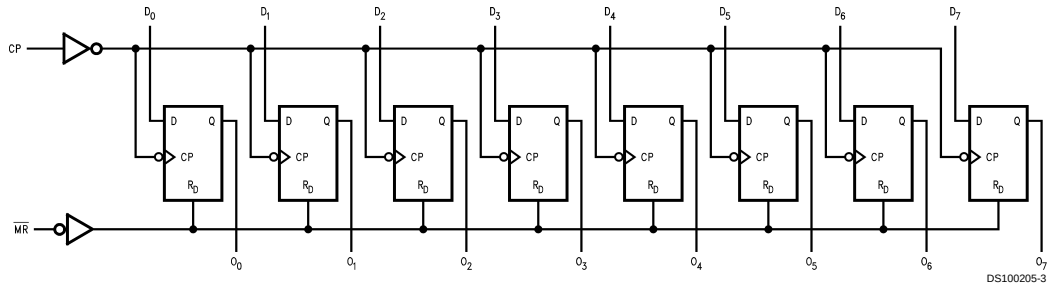
Truth Table

H = HIGH Voltage Level steady state
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH clock transition
L = LOW Voltage Level steady state
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH clock transition
X = Immaterial
⌐ = LOW-to-HIGH clock transition

Mode Select-Function Table

Operating Mode	Inputs			Output
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load “1”	H	⌐	h	H
Load “0”	H	⌐	l	L

Logic Diagram



DS100205-3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature	−65˚C to +150˚C
Ambient Temperature under Bias	−55˚C to +125˚C
Junction Temperature under Bias	
Ceramic	−55˚C to +175˚C
V_{CC} Pin Potential to	
Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to +4.75V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
(Across Comm Operating Range)	
Over Voltage Latchup	V_{CC} + 4.5V

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55˚C to +125˚C
Supply Voltage	
Military	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		ABT273 Min	ABT273 Typ	ABT273 Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54ABT	2.5					I_{OH} = −3 mA
		54ABT	2.0			V	Min	I_{OH} = −24 mA
V_{OL}	Output LOW Voltage	54ABT			0.55	V	Min	I_{OL} = 48 mA
I_{IH}	Input HIGH Current				5	μA	Max	V_{IN} = 2.7V (Note 4)
					5			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−5	μA	Max	V_{IN} = 0.5V (Note 4)
					−5			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA
								All Other Pins Grounded
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCT}	Maximum I_{CC}/Input	Outputs Enabled						V_I = V_{CC} − 2.1V
					1.5	mA	Max	Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC}	No Load			0.3	mA/ MHz	Max	Outputs Open (Note 3)
								One Bit Toggling, 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.5 mA/MHz.

Note 4: Guaranteed but not tested.

AC Electrical Characteristics

Symbol	Parameter	54ABT $T_A = -55^\circ C$ to $+125^\circ C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	
f_{max}	Max Clock Frequency	150		MHz
t_{PLH}	Propagation Delay	1.0	7.0	ns
t_{PHL}	CP to O_n	1.0	7.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to O_n	1.0	8.2	ns

AC Operating Requirements

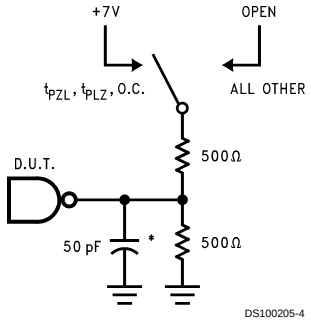
Symbol	Parameter	54ABT $T_A = -55^\circ C$ to $+125^\circ C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	
$t_s(H)$	Setup Time, HIGH	2.0		ns
$t_s(L)$	or LOW D_n to CP	2.5		
$t_h(H)$	Hold Time, HIGH	1.4		ns
$t_h(L)$	or LOW D_n to CP	1.4		
$t_w(H)$	Pulse Width, CP,	3.3		ns
$t_w(L)$	HIGH or LOW	3.3		
$t_w(L)$	Master Reset Pulse Width, LOW	3.3		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	2.0		ns

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25^\circ C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-833B, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

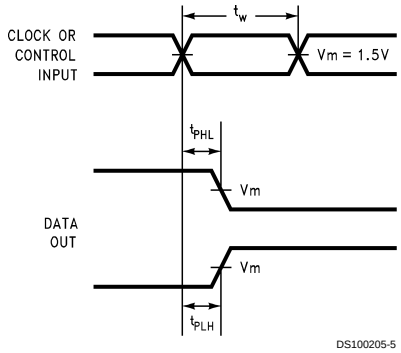


FIGURE 2. Propagation Delay, Pulse Width Waveforms

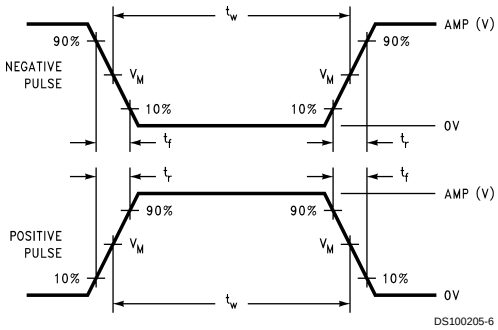


FIGURE 3. V_M = 1.5V Input Pulse Requirements

Amplitude	Rep. Rate	t_w	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 4. Test Input Signal Requirements

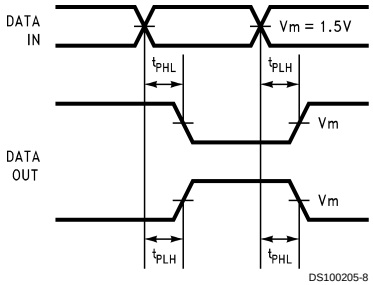


FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

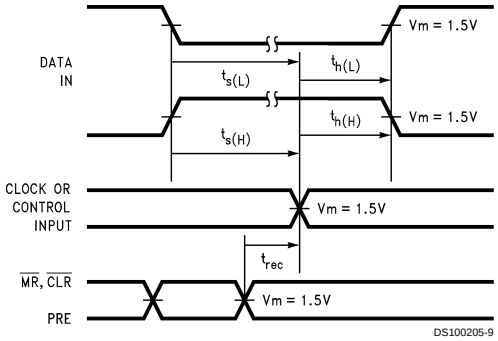
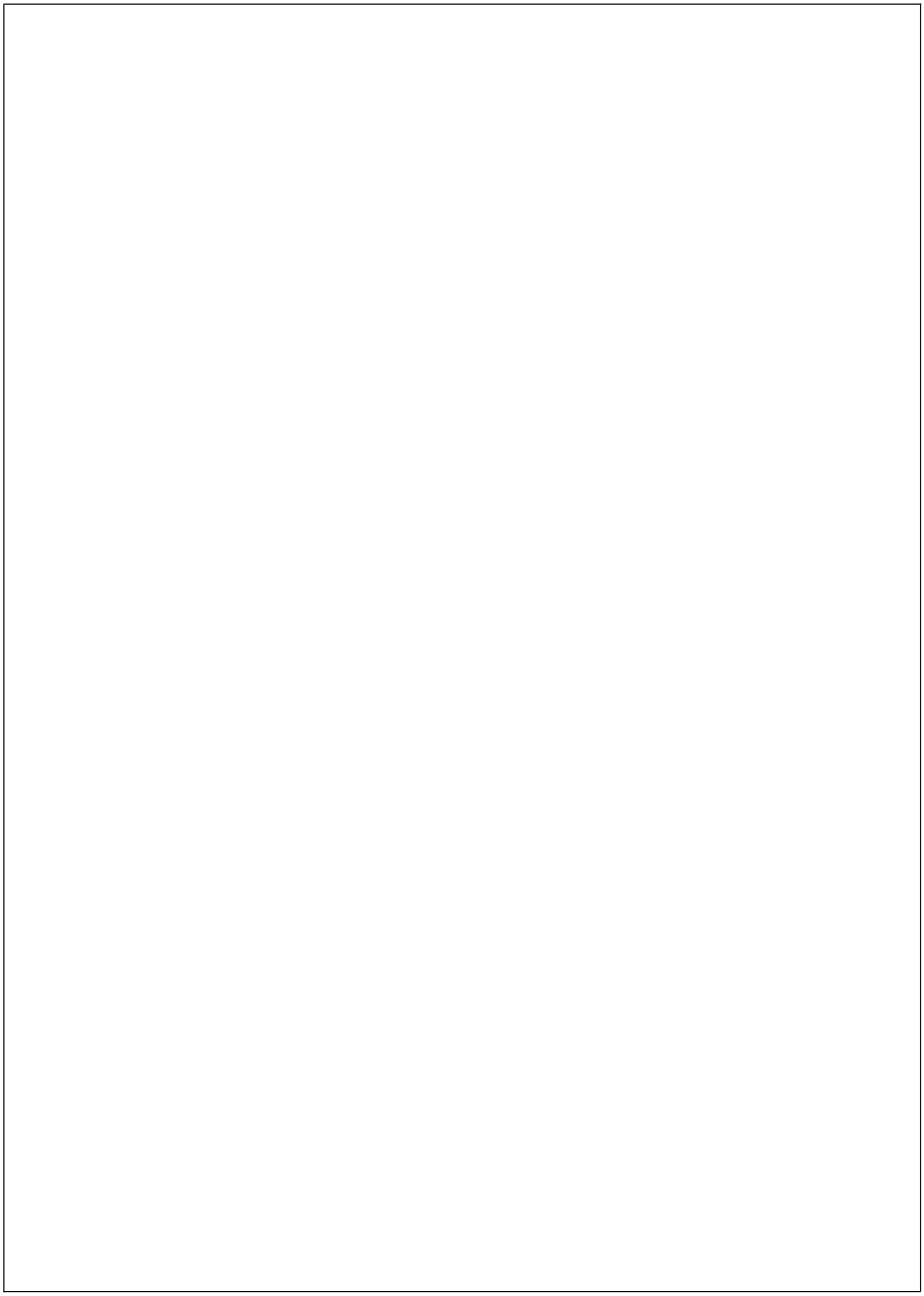
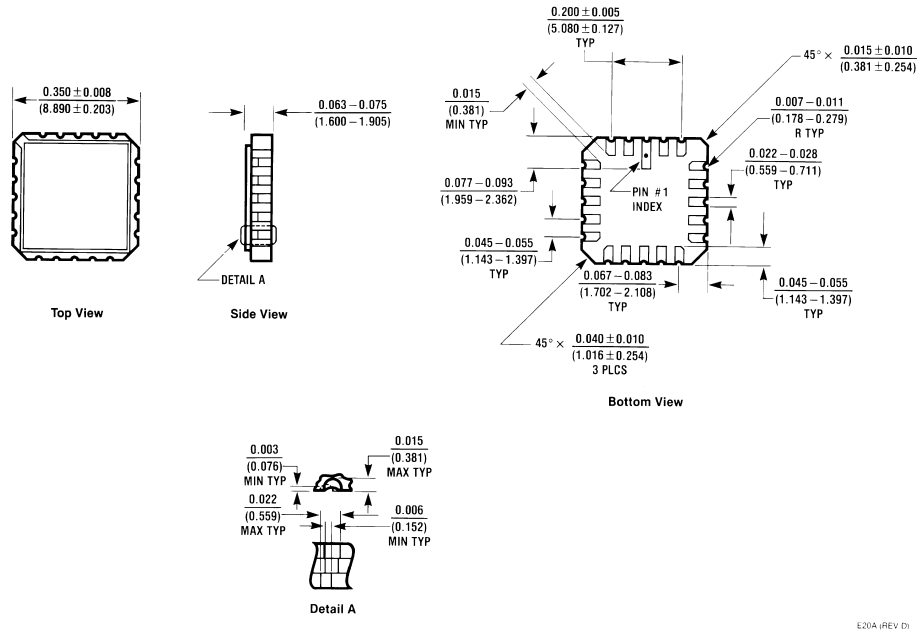


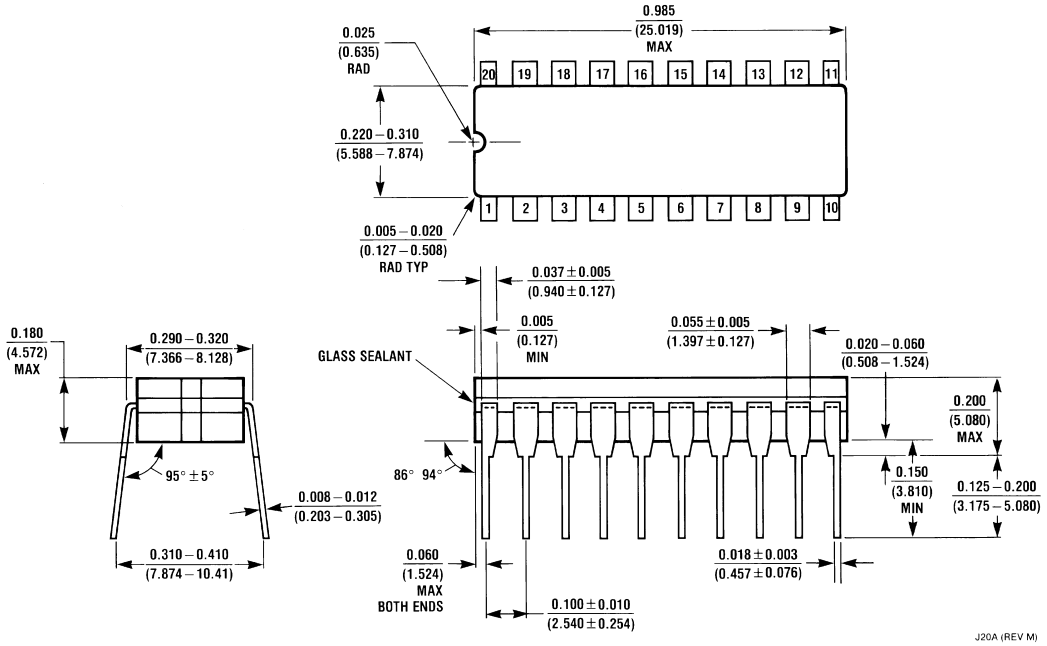
FIGURE 6. Setup Time, Hold Time and Recovery Time Waveforms



Physical Dimensions inches (millimeters) unless otherwise noted

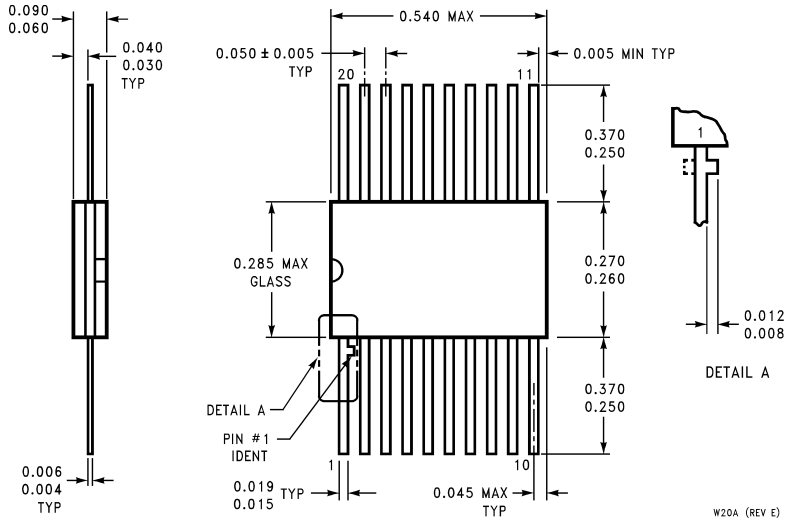


20-Terminal Ceramic Chip Carrier (L)
NS Package Number E20A



20-Lead Ceramic Dual-In-Line (D)
NS Package Number J20A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Ceramic Flatpak (F)
NS Package Number W20A

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